	SN74BCT29864B 9-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS SCBS010A – NOVEMBER 1988 – REVISED NOVEMBER 1993
<ul> <li>BiCMOS Design Substantially Reduces Standby Current</li> </ul>	DW OR NT PACKAGE (TOP VIEW)
<ul> <li>Functionally Equivalent to 'ALS29864 and AMD Am29864A</li> </ul>	$\begin{array}{c c} \hline OEBA1 & \hline 1 & 24 \\ \hline A1 & 2 & 23 \\ \hline B1 & B1 \end{array}$
Power-Up High-Impedance State	A1 U 2 23 U B1 A2 U 3 22 U B2
<ul> <li>ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015</li> </ul>	A3 [] 4 21 ]] B3 A4 [] 5 20 ]] B4
Package Options Include Plastic	A5 🛛 6 19 🗋 B5
Small-Outline (DW) Packages and Standard	A6 [] 7 18 [] B6
Plastic 300-mil DIPs (NT)	
description	
description	
This 9-bit transceiver is designed for asynchronous communication between data	OEBA2   11 14   OEAB2 GND   12 13   OEAB1

buses. The control-function implementation allows for maximum flexibility in timing.

The device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the output-enable (OEBA and OEAB) inputs.

The outputs are in the high-impedance state during power-up and power-down conditions. The outputs remain in the high-impedance state while the device is powered-down.

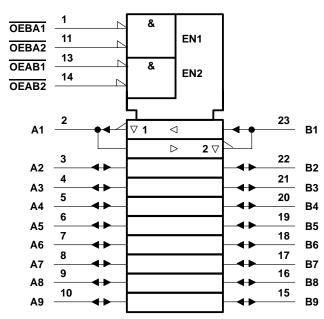
	FUNCTION TABLE							
INPUTS			OPERATION					
OEAB1	OEAB2	OEBA1	OEBA2	OPERATION				
L	L	L	L	Latch A and B				
L	L	Н	Х	A to B				
L	L	Х	Н	A IO B				
н	Х	L	L	B to A				
Х	Н	L	L	B IO A				
н	Х	Н	Х					
н	Х	Х	Н	Isolation				
X	Н	Х	Н	1501411011				
Х	Н	Н	Х					

The SN74BCT29864B is characterized for operation from 0°C to 70°C.

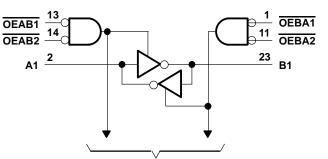
# SN74BCT29864B 9-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

SCBS010A - NOVEMBER 1988 - REVISED NOVEMBER 1993

## logic symbol<sup>†</sup>



logic diagram (positive logic)



To Eight Other Channels

<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage range, V <sub>CC</sub> Input voltage range (I/O ports) (see Note 1) Input voltage range (excluding I/O ports) (see Note 1) Voltage range applied to any output in the high state Input clamp current Current into any output in the low state Operating free-air temperature range	$\begin{array}{cccc} -0.5 \ V \ to \ 5.5 \ V \\ -0.5 \ V \ to \ 7 \ V \\ -0.5 \ V \ to \ 7 \ V \\ -0.5 \ V \ to \ V_{CC} \\ -30 \ mA \\ -96 \ mA \\ -0^{\circ}C \ to \ 70^{\circ}C \end{array}$
Storage temperature range	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
 NOTE 1: The negative voltage rating may be exceeded if the input current rating is observed.

## recommended operating conditions

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
Iк	Input clamp current			-18	mA
IOH	High-level output current			-24	mA
IOL	Low-level output current			48	mA
TA	Operating free-air temperature	0		70	°C



## SN74BCT29864B 9-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

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### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MAX	UNIT	
VIK		V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = -18 mA -		-1.2	V			
			I <sub>OH</sub> = -15 mA	2.4	3.3			
VOH		V <sub>CC</sub> = 4.5 V	$I_{OH} = -24 \text{ mA}$	2	3.1		V	
		V <sub>CC</sub> = 4.75 V,	$I_{OH} = -3 \text{ mA}$	2.7				
VOL		V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA		0.35	0.5	V	
Ц		V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 5.5 V			0.1	mA	
Control inputs			1 07/1			20		
ЧΗ	A or B port‡	$V_{CC} = 5.5 V,$	V <sub>I</sub> =27.7′ ∨			20	μA	
l.	Control inputs		V05V.v			-0.2	~^	
ΊĽ	A or B port‡	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 05.5′ v			-0.2	mA	
IIO(off)	)§	$V_{CC} = 0,$	V <sub>O</sub> = 2.7 V			0.1	mA	
los¶		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0	-75		-250	mA	
lcc			Outputs high		18	30		
		V <sub>CC</sub> = 5.5 V	Outputs low		30	45	mA	
			Outputs disabled		6.5	12		
Ci		V <sub>CC</sub> = 5 V,	$V_{I} = 0.5 V \text{ or } 2.5 V$		6		pF	
C <sub>io</sub>		V <sub>CC</sub> = 5 V,	$V_{I} = 0.5 V \text{ or } 2.5 V$		8		pF	

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C. <sup>‡</sup> For I/O ports, the parameters I<sub>IH</sub> and I<sub>IL</sub> include the off-state output current.

§ IO(off) = Power-off bus leakage current

Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

## switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	ТО (ОИТРИТ)	CL R1 R2 T <sub>A</sub>	C = 5 V, = 50 pF = 500 $\Omega$ = 500 $\Omega$ = 25°C	;, ), ),	C <sub>L</sub> = 50 p R1 = 500 g R2 = 500 g T <sub>A</sub> = MIN	ດ, ດ, to MAX <sup>#</sup>	UNIT
			MIN	TYP	MAX	MIN	MAX	
<sup>t</sup> PLH	A or B	B or A	1	3.5	5.3	1	6.1	ns
<sup>t</sup> PHL		DOIX	0.5	2.3	4.6	0.5	4.8	115
<sup>t</sup> PZH	OEAB or OEBA	A or B	2.3	5	7.2	2.3	8.4	
<sup>t</sup> PZL		AUB	4.3	7.3	10.6	4.3	12.5	ns
<sup>t</sup> PHZ	OEAB or OEBA	A or B	2.3	4.6	7.6	2.3	8.4	
<sup>t</sup> PLZ		AUIB	2	4	7	2	8.2	ns

<sup>#</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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